

DESCRIPTION

- Collector–Emitter Sustaining Voltage
: $V_{CEO(SUS)} = 450V(\text{Min.})$
- Collector Saturation Voltage
: $V_{CE(sat)} = 0.3V(\text{Max}) @ I_C = 1.0A$
- Very High Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

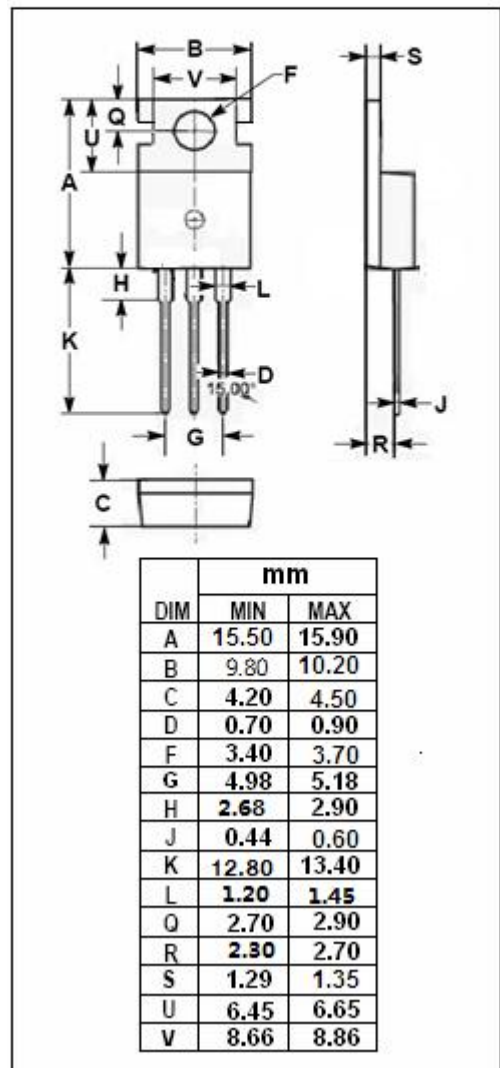
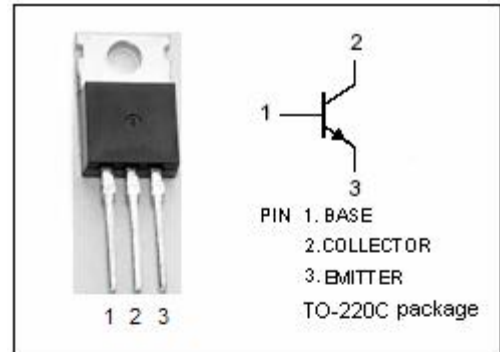
- Electronic transformers for halogen lamps
- Flyback and forward single transistor low power converters

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

| SYMBOL | PARAMETER | VALUE | UNIT |
|-----------|---|---------|------------------|
| V_{CES} | Collector-Emitter Voltage | 850 | V |
| V_{CEO} | Collector-Emitter Voltage | 450 | V |
| V_{EBO} | Emitter-Base Voltage | 10 | V |
| I_C | Collector Current-Continuous | 5 | A |
| I_{CM} | Collector Current-peak $t_p < 5\text{ms}$ | 10 | A |
| I_B | Base Current-Continuous | 2 | A |
| I_{BM} | Base Current-peak $t_p < 5\text{ms}$ | 4 | A |
| P_C | Collector Power Dissipation $T_C=25^\circ\text{C}$ | 80 | W |
| T_j | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{stg} | Storage Temperature Range | -65~150 | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------|---|------|--------------------|
| $R_{th\ j-c}$ | Thermal Resistance, Junction to Case | 1.56 | $^\circ\text{C/W}$ |
| $R_{th\ j-A}$ | Thermal Resistance, Junction to Ambient | 62.5 | $^\circ\text{C/W}$ |



ELECTRICAL CHARACTERISTICS

 T_C =25°C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|---------------------------------|--------------------------------------|--|-----|------|------------|------|
| V _{CE(SUS)} | Collector-Emitter Sustaining Voltage | I _C = 10mA; L= 25mH | 450 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = 10mA; I _C = 0 | 10 | | | V |
| V _{CE(sat)-1} | Collector-Emitter Saturation Voltage | I _C = 1A; I _B = 0.2A | | | 0.3 | V |
| V _{CE(sat)-2} | Collector-Emitter Saturation Voltage | I _C = 2A; I _B = 0.4A | | | 0.6 | V |
| V _{CE(sat)-3} | Collector-Emitter Saturation Voltage | I _C = 4A; I _B = 0.8A | | | 1.2 | V |
| V _{BE(sat)-1} | Base-Emitter Saturation Voltage | I _C = 1A; I _B = 0.2A | | | 1.0 | V |
| V _{BE(sat)-2} | Base-Emitter Saturation Voltage | I _C = 4A; I _B = 0.8A | | | 1.3 | V |
| I _{CES} | Collector Cutoff Current | V _{CE} = 850V; V _{BE} = 0 V _{CE} = 850V; V _{BE} = 0, T _C = 125°C | | | 0.1 0.5 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 9V; I _C = 0 | | | 0.1 | mA |
| h _{FE-1} | DC Current Gain | I _C = 10mA; V _{CE} = 5V | 10 | | | |
| h _{FE-2} | DC Current Gain | I _C = 0.5A; V _{CE} = 5V | | | 60 | |
| h _{FE-3} | DC Current Gain | I _C = 7A; V _{CE} = 10V | 4 | | 10 | |
| Switching Times, Resistive Load | | | | | | |
| t _s | Storage Time | I _C = 2A; V _{CC} = 250V; I _{B1} = -I _{B2} = 0.4A | | | 3 | μs |
| t _f | Fall Time | | | | 0.8 | μs |

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